NSN 5961-01-205-7395

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Inclosure Material:



View Online at https://aerobasegroup.com/nsn/5961-01-205-7395

Metal
Overall Length:
0.260 inches
Terminal Length:
0.500 inches
Overall Diameter:
0.370 inches
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-5
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Terminal
Terminal Circle Diameter:
0.200 inches
Features Provided:
Hermetically sealed case and quality assurance level txv
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
140.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage,
static, collector open
Current Rating Per Characteristic:
1.00 amperes source cutoff current
Power Rating Per Characteristic:
5.0 watts small-signal input power, common-collector preset
Transfer Ratio:
300.0 static forward current transfer ratio, common-emitter
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Test Data Document:
81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:

NI/o

Shelf Life:

3 uninsulated wire lead **Specification Data:**

81349-mil-prf-19500/391 government specification

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Demilitarization:

No

Fiig:

A110a0

Mil-std (military Standard):

Mil-prf-19500 spec.